

## SCHOTTKY BARRIER RECTIFIER DIODES

VOLTAGE RANGE: 40V CURRENT: 1.0 A

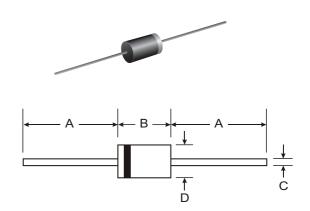
## **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications

## **Mechanical Data**

- Case:DO-41, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number





DO-41				
Dim	Min	Max		
Α	25.40	_		
В	4.06	5.21		
С	0.71	0.864		
D	2.00	2.72		
All Dimensions in mm				

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

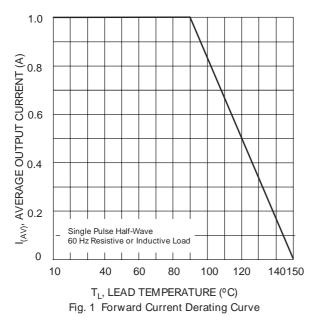
Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

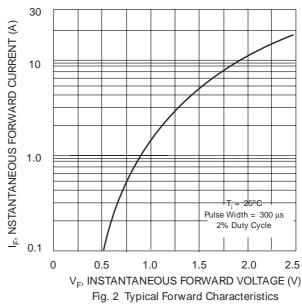
Characteristic		Symbol	EK14	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	40	V
RMS Reverse Voltage		VR(RMS)	28	V
Average Rectified Output Current (Note 1)	@T <sub>L</sub> = 90°C	lo	1.0	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	25	А
Forward Voltage	$@I_F = 1.0A$ $@I_F = 3.0A$	VFM	0.60 0.90	V
Peak Reverse Current At Rated DC Blocking Voltage	@T <sub>A</sub> = 25°C @T <sub>A</sub> = 100°C	IRM	1.0 10	mA
Typical Junction Capacitance (Note 2)		Cj	110	pF
Typical Thermal Resistance Junction to Lead (Note 1)		$R_{\theta}$ JL	60	K/W
Operating and Storage Temperature Range		Тj, Tsтg	-65 to +150	°C

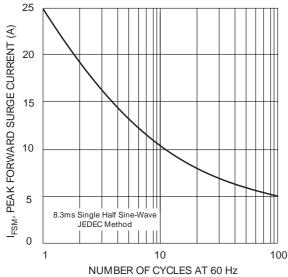
Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

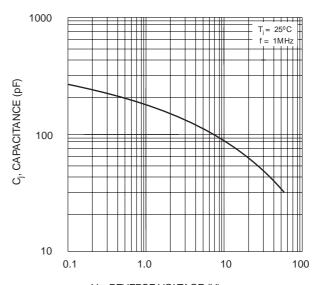








100 Fig. 3 Maximum Non-Repetitive Peak Fwd Surge Current



 $V_{R^{\dagger}}$  REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance